

**IN THE SPECIFICATION:**

**Please rewrite** the paragraph at page 2, line 27 to page 3, line 21, so that it reads as follows:

FIG. 2b is a sectional view of c-c' according to FIG. 2a. As shown in FIG. 2b, an indium tin oxide layer 31 is disposed in the indium tin oxide region 5. The opening region 51 is defined where the indium tin oxide layer 31 contacts the organic illuminating material 32. In FIG. 2b, a metal layer 34 (aluminum) and the indium tin oxide layer 31 are respectively utilized as anode and cathode such that the organic illuminating material 32 disposed therebetween is electrically driven to illuminate. Additionally, with respect to the isolation region 52, the periphery of the indium tin oxide layer 31 is separated from the organic illuminating material 32 by a silicon nitride (SiN) isolation layer 33.

**Please rewrite** the paragraph at page 5, lines 8-21, so that it reads as follows:

FIG. 3a is a top view of a pixel unit in the active-matrix organic light emitting diode (AM-OLED) display in accordance with the present invention. Referring to FIG. 3a, a pixel unit 3 is provided with a first thin film transistor region 71 disposed at the left side, a capacitor region 72 disposed at the top side, a second thin film transistor region 73 disposed at the bottom side and an indium tin oxide region 8. The first thin film transistor region 71, capacitor region 72 and second thin film transistor region 73 form an active control region and are appropriately arranged around the indium tin oxide region 8 in hoof shape as shown in FIG. 3a such that the indium tin oxide region 8 forms a rectangle occupying the central and right parts of the pixel unit 3.